Unit: mm

TOSHIBA GTR Module Silicon N Channel IGBT

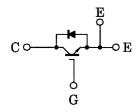
MG400J1US51

High Power Switching Applications Motor Control Applications

- The electrodes are isolated from case.
- High input impedance
- Includes a complete half bridge in one package.
- Enhancement-mode
- High speed : $t_f = 0.30\mu s$ (Max.) (IC = 400A) $t_{rr} = 0.15\mu s$ (Max.) (IF = 400A)
- Low saturation voltage

 $: V_{CE (sat)} = 2.70 V (Max.) (I_{C} = 400 A)$

Equivalent Circuit



2-M4 2-M6 4-\$\phi 6.5 \pm 0.3 \\ \text{2-M4} \text{2-M6} \text{4-\$\phi 6.5 \pm 0.3} \\ \text{2-M4} \text{2-M6} \text{4-\$\phi 6.5 \pm 0.3} \\ \text{2-M4} \text{2-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{2-M4} \text{2-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{2-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{3-M6} \text{3-M6} \\ \text{3-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{3-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{3-M6} \\ \text{3-M6} \text{4-\$\phi 6.5 \pm 0.5} \\ \text{3-M6} \\ \text{

Weight: 465g (Typ.)

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C	400	Α	
	1ms	I _{CP}	800	A	
Forward current	DC	l _F	400	Α	
	1ms	I _{FM}	800	A	
Collector power dissipation (Tc = 25°C)		P _C	1500	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	- 40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 min.)	٧	
Screw torque (Terminal / M4 / M6 / mounting)		_	2/3/3	N·m	

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damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

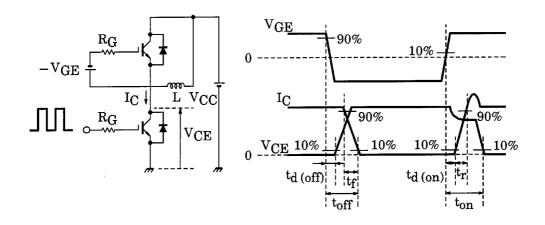
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Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 600V, V _{GE} = 0	_	_	4.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 40mA, V _{CE} = 5V	5.0	7.0	8.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 400A, V _{GE} = 15V	_	2.10	2.70	V
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	36000	_	pF
Switching time	Turn-on delay time	t _{d (on)}	Inductive load $V_{CC}=300V$ $I_{C}=400A$ $V_{GE}=\pm15V$ $R_{G}=2\Omega$ (Note 1)	_	0.20	0.40	μs
	Rise time	t _r		_	0.15	0.30	
	Turn-on time	t _{on}		_	0.60	1.20	
	Turn-off delay time	t _{d (off)}		_	0.20	0.40	
	Fall time	t _f		_	0.15	0.30	
	Turn-off time	t _{off}		_	0.50	1.00	
Forward voltage		V _F	I _F = 400 A, V _{GE} = 0	_	2.30	3.00	V
Reverse recovery time		t _{rr}	I _F = 400 A, V _{GE} = -10 V, di / dt = 400 A / μs	_	0.08	0.15	μs
Thermal resistance		R _{th (j-c)}	Transistor stage	_	_	0.083	°C/W
			Diode stage	_	_	0.20	

Note 1: Switching time test circuit & timing chart

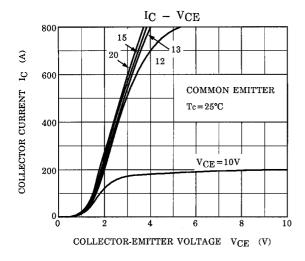


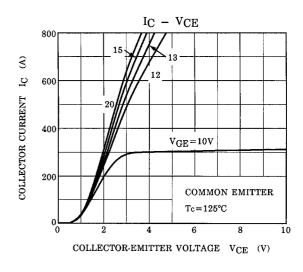
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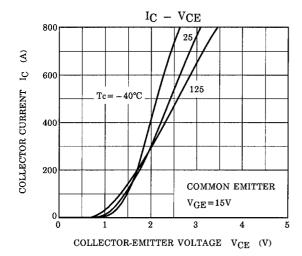
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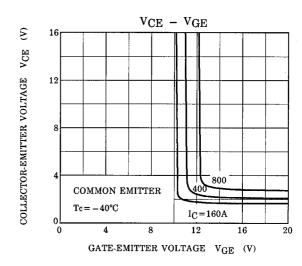
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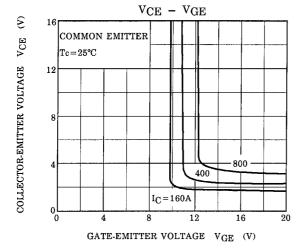
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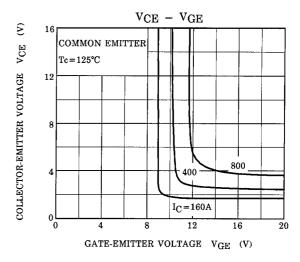


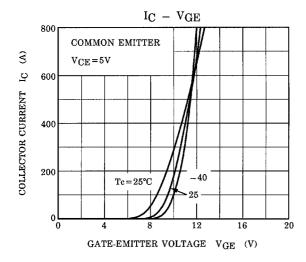


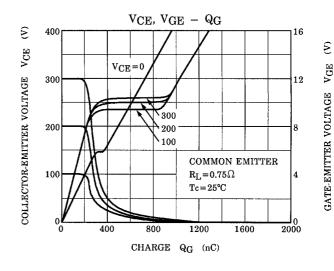


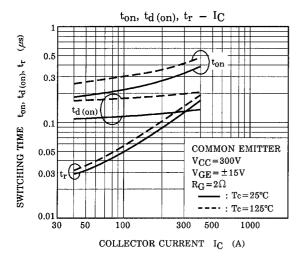


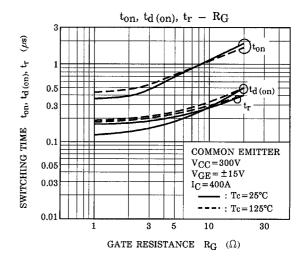


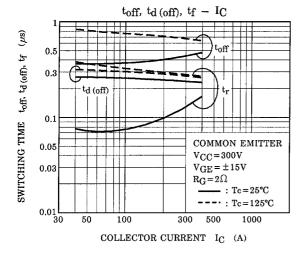


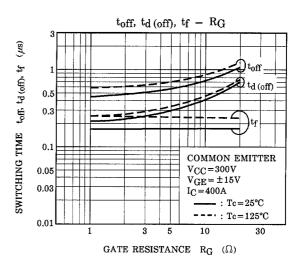


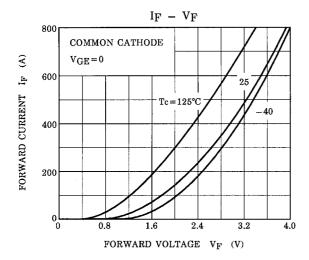


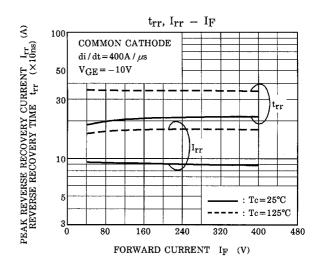


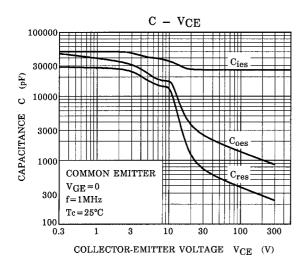


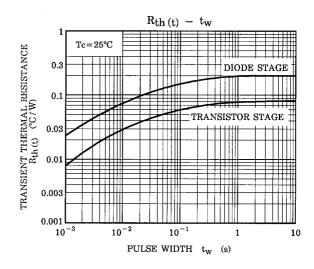


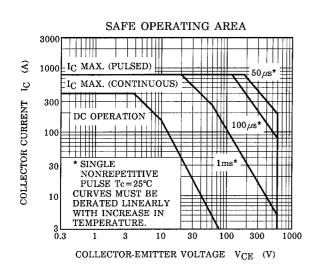


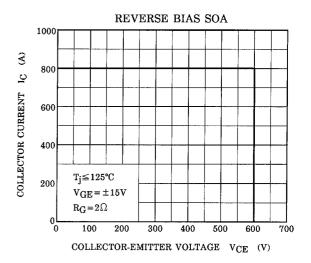












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